SWITCHMODE [™] **Soft Recovery Power Rectifier**

Plastic TO-220 Package

These state-of-the-art devices are designed for use as free wheeling diodes in variable speed motor control applications and switching power supplies.

Features

- Soft Recovery with Guaranteed Low Reverse Recovery Charge (Q_{RR}) and Peak Reverse Recovery Current (I_{RRM})
- 150°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy meets UL 94 V-0 @ 0.125 in
- Low Forward Voltage
- Low Leakage Current
- High Temperature Glass Passivated Junction
- Pb-Free Package is Available*

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	600	٧
Average Rectified Forward Current (Rated V _R , T _C = 125°C)	Io	8.0	Α
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz, T _C = 125°C)	I _{FRM}	16	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	100	Α
Storage/Operating Case Temperature	T _{stg} , T _C	-65 to +150	°C
Operating Junction Temperature	TJ	-65 to +150	°C

THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case Thermal Resistance, Junction-to-Ambient	$R_{ heta JC} \ R_{ heta JA}$	1.6 72.8	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

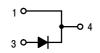
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

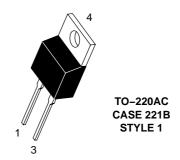


ON Semiconductor®

http://onsemi.com

SOFT RECOVERY POWER RECTIFIER 8.0 AMPERES, 600 VOLTS





MARKING DIAGRAM



A = Assembly Location

Y = Year
WW = Work Week
G = Pb-Free Package
KA = Diode Polarity

ORDERING INFORMATION

Device	Package	Shipping
MSR860	TO-220	50 Units/Rail
MSR860G	TO-220 (Pb-Free)	50 Units/Rail

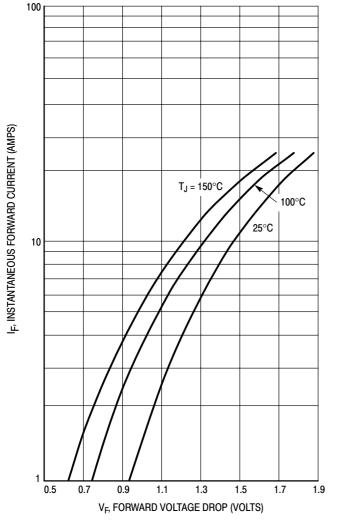
ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Va	lue	Unit
Maximum Instantaneous Forward Voltage (Note 1)	V _F	T _J = 25°C	T _J = 150°C	V
(I _F = 8.0 A) Typical		1.7 1.4	1.3 1.1	
Maximum Instantaneous Reverse Current	I _R	T _J = 25°C	T _J = 150°C	μΑ
(V _R = 600 V) Typical		10 2.0	1000 80	
Maximum Reverse Recovery Time (Note 2)	t _{rr}	T _J = 25°C	T _J = 125°C	ns
$(V_R = 400 \text{ V}, I_F = 8.0 \text{ A}, \text{ di/dt} = 200 \text{ A/}\mu\text{s})$ Typical		120 95	190 125	
Typical Recovery Softness Factor $(V_R = 400 \text{ V}, I_F = 8.0 \text{ A}, \text{di/dt} = 200 \text{ A/}\mu\text{s})$	$s = t_b/t_a$	2.5	3.0	
Maximum Peak Reverse Recovery Current ($V_R = 400 \text{ V}, I_F = 8.0 \text{ A}, \text{ di/dt} = 200 \text{ A/}\mu\text{s}$)	I _{RRM}	5.8	8.3	А
Maximum Reverse Recovery Charge ($V_R = 400 \text{ V}, I_F = 8.0 \text{ A}, \text{ di/dt} = 200 \text{ A/}\mu\text{s}$)	Q _{RR}	350	700	nC

- 1. Pulse Test: Pulse Width \leq 380 $\mu s,$ Duty Cycle \leq 2%
- 2. $T_{\mbox{\scriptsize RR}\mbox{\scriptsize M}}$ measured projecting from 25% of $I_{\mbox{\scriptsize RRM}}$ to zero current

TYPICAL ELECTRICAL CHARACTERISTICS

100



T_J = 150°C

T_J = 150°C

100°C

100°C

100°C

100°C

V_R, REVERSE VOLTAGE (VOLTS)

Figure 2. Typical Reverse Current

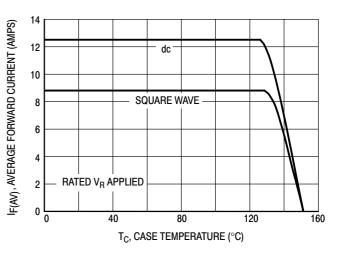


Figure 1. Typical Forward Voltage

Figure 3. Current Derating, Case

TYPICAL ELECTRICAL CHARACTERISTICS

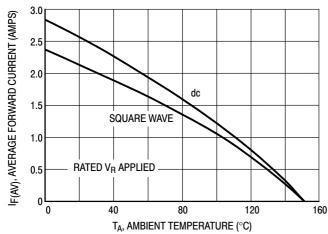


Figure 4. Current Derating, Ambient

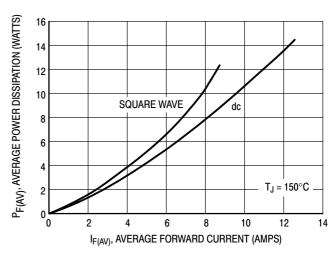


Figure 5. Power Dissipation

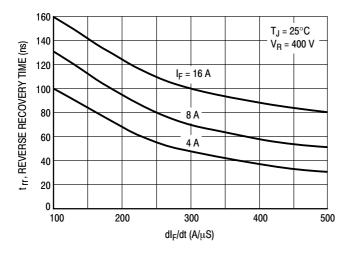


Figure 6. Typical Reverse Recovery Time

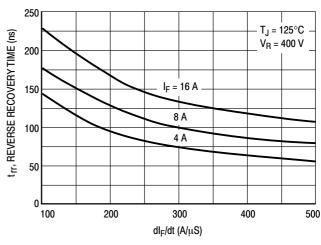


Figure 7. Typical Reverse Recovery Time

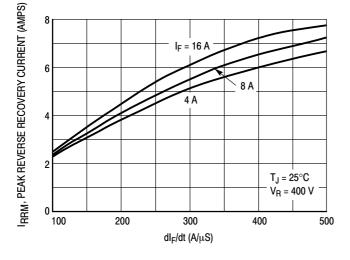


Figure 8. Typical Peak Reverse Recovery Current

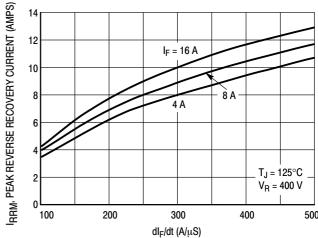
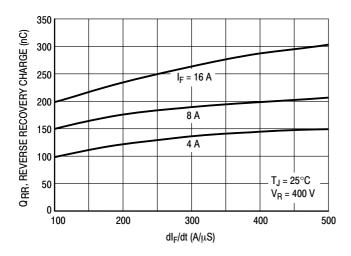


Figure 9. Typical Peak Reverse Recovery Current

TYPICAL ELECTRICAL CHARACTERISTICS



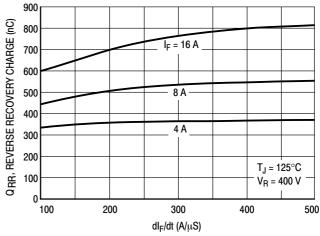
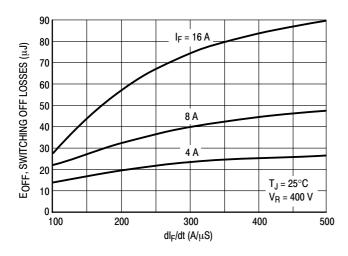


Figure 10. Typical Reverse Recovery Charge

Figure 11. Typical Reverse Recovery Charge



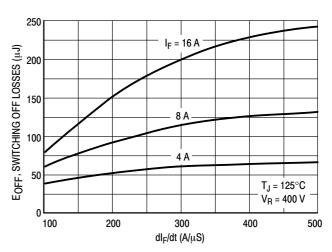


Figure 12. Typical Switching Off Losses

Figure 13. Typical Switching Off Losses

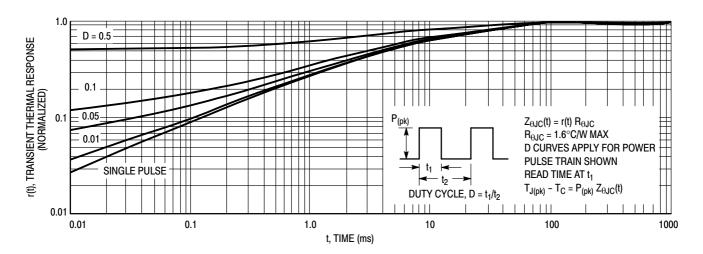
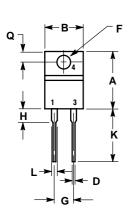


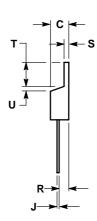
Figure 14. Thermal Response

PACKAGE DIMENSIONS

TO-220 TWO-LEAD

CASE 221B-04 ISSUE D





NOTES

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.595	0.620	15.11	15.75
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.82
D	0.025	0.035	0.64	0.89
F	0.142	0.147	3.61	3.73
G	0.190	0.210	4.83	5.33
Н	0.110	0.130	2.79	3.30
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
Т	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27

STYLE 1:

PIN 1. CATHODE

- 3. ANODE 4. CATHODE

SWITCHMODE is a trademark of Semiconductor Components Industries, LLC.

ON Semiconductor and un are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice on semiconductor and are registered readerlands of semiconductor Components industries, Ltc (SCILLC). Solitude services the inject that changes without further holice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications. intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082-1312 USA Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free

Japan: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.